1. Krets

1.1. Elements

1.1.1. Diode

The diode is modeled as a nonlinear element with a current-voltage relationship defined by the Shockley diode equation:

$$I_D = I_S \left(e^{\frac{V_D}{nV_T}} - 1 \right) \tag{1}$$

Where I_D is the diode current, I_S is the reverse saturation current, V_D is the voltage across the diode, V_T is the thermal voltage, and, n is the ideality factor, also known as the quality factor, emission coefficient, or the material constant.

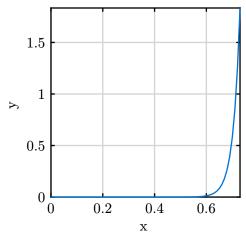


Figure 1: Diode IV Curve

The conductance of the diode is G_D and is given by the derivative of the Shockley diode equation with respect to the voltage:

$$G_D = \frac{dI_D}{dV_D} = \frac{I_S}{nV_T} e^{\frac{V_D}{nV_T}} \tag{2}$$

1.1.2. Voltage Source

In the conductance matrix the stamps for a voltage source are given by:

If the positive terminal is connect to node i and the node is not grounded, the stamp is: 1

1.2. Analyses

1.2.1. DC

During DC analysis, the circuit is analyzed under steady-state conditions with all capacitors treated as open circuits and all inductors treated as short circuits.

1.2.1.1. Diode IV Curve

$$\begin{cases} V_1 = 1 \\ R_1 = 1000 \end{cases}$$

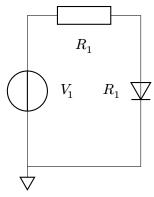


Figure 2: Diode IV Curve

$$I_D = \frac{V_{\text{out}} - V_1}{R_1} \tag{3}$$

$$I_D = I_S \left(e^{\frac{V_D}{nV_T}} - 1 \right) \tag{4}$$

We guess the diode voltage $V_D=0.5$ and calculate the diode current I_D using the Shockley diode equation.

$$I_D = 0.000250974909997991 (5)$$

$$G_{\rm eq} = 0.009708143009102018 \tag{6}$$

Then we solve for V_{out} :

$$V_{\rm out} = I_D R_1 + V_{\rm in} = 1.250974909997991$$

Now we can calculate ${\cal I}_D$ again using the Shockley diode equation with the new ${\cal V}_D$:

$$I_D = 1036223743.738507 \tag{7}$$

A Appendix

A.1 Constants

The following physical constants are used throughout this document:

 $k_B = 1.380649 \cdot 10^{-23}$ (Boltzmann constant)

 $q = 1.602176634 \cdot 10^{-19}$ (Elementary charge)

T = 300 (Standard temperature)

 $V_T = \frac{k_B T}{q} \approx 0.02585$ (Thermal voltage at 300K)

 $I_S = 1 \cdot 10^- 12$ (reverse saturation current)

0.000000000001